

RN1111ACT(TPL3)

RN1111ACT(TPL3) Information

www.weilsentec.com	RN1111ACT(TPL3) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single, Pre-Biased TRANS PREBIAS NPN 0.1W CST3 SC-101, SOT-883 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RN1111ACT(TPL3) Specifications

	Report errors?
Supplier Device Package	CST3
Package / Case	SC-101, SOT-883
Mounting Type	Surface Mount
Power - Max	100mW
Frequency - Transition	-
Current - Collector Cutoff (Max)	100nA (ICBO)
Vce Saturation (Max) @ Ib, Ic	150mV @ 250µA, 5mA
DC Current Gain (hFE) (Min) @ Ic, Vce	120 @ 1mA, 5V
Resistor - Emitter Base (R2) (Ohms)	-
Resistor - Base (R1) (Ohms)	10k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	80mA
Transistor Type	NPN - Pre-Biased
Series	-
Package	SC-101, SOT-883
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	Toshiba Semiconductor and Storage
Manufacturer Part Number	RN1111ACT(TPL3)

RN1111ACT(TPL3) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1111ACT(TPL3) Payment Methods



RN1111ACT(TPL3) Shipping Methods



If you have any question about RN1111ACT(TPL3), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com